· Low forward voltage drop, low power losses

Vishay General Semiconductor

- 10 s per JESD 22-B106
- AEC-Q101 gualified available - Automotive ordering code: base P/NHM3
- please see www.vishay.com/doc?99912

NS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and

ng d

| MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | | | | | | |
|--|------------|-------------------------------|----------------------|------|--|--|--|--|--|
| PARAMETER | | SYMBOL | VX20202C | UNIT | | | | | |
| Maximum repetitive peak reverse voltage | | V _{RRM} | V _{RRM} 200 | | | | | | |
| Maximum average forward rectified current | per device | | 20 | ٨ | | | | | |
| (fig. 1) | per diode | IF(AV) | 10 | — A | | | | | |
| Peak forward surge current 8.3 ms single half superimposed on rated load | sine-wave | I _{FSM} | 150 | А | | | | | |
| Operating junction temperature range | | T _J ⁽¹⁾ | -40 to +175 | | | | | | |
| Storage temperature range | | T _{STG} | -40 to +175 | U U | | | | | |

Note

⁽¹⁾ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{0,JA}$

Dual High Voltage TMBS[®] (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.58$ V at $I_F = 5.0$ A

FEATURES

- Trench MOS Schottky technology
- · High efficiency operation
- Solder bath temperature 275 °C maximum,
- - Material categorization: for definitions of compliance

| TYPICAL | APPLICATION |
|---------|-------------|
| | |

automotive application.

MECHANICAL DATA

| Case: TO-220AB |
|---|
| Molding compound meets UL 94 V-0 flammability ratin |
| Base P/N-M3 - halogen-free, RoHS-compliant |
| Base P/NHM3_X - halogen-free, RoHS-compliant, and |
| AEC-Q101 qualified |
| |

("_X" denotes revision code e.g. A, B,....)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102 M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Mounting torque: 10 in-lbs maximum

TO-220AB PIN 1 O PIN 2 CASE

| PRIMARY CHARACTERISTICS | | | | | | | |
|---|----------------|--|--|--|--|--|--|
| I _{F(AV)} | 2 x 10 A | | | | | | |
| V _{RRM} | 200 V | | | | | | |
| I _{FSM} | 150 A | | | | | | |
| V_F at I_F = 10 A (T_J = 125 °C) | 0.65 V | | | | | | |
| T _J max. | 175 °C | | | | | | |
| Package | TO-220AB | | | | | | |
| Circuit configuration | Common cathode | | | | | | |







COMPLIANT

HALOGEN

FREE







Vishay General Semiconductor

| ELECTRICAL CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise noted) | | | | | | | | | |
|---|------------------------|-------------------------|-------------------------------|--------|------|------|--|--|--|
| PARAMETER | TEST CO | NDITIONS | SYMBOL | TYP. | MAX. | UNIT | | | |
| | I _F = 2.5 A | | V _F ⁽¹⁾ | 0.68 | - | | | | |
| | I _F = 5 A | T _J = 25 °C | | 0.73 | - | V | | | |
| Instantaneous forward valtage per diade | I _F = 10 A | | | 0.79 | 0.84 | | | | |
| Instantaneous forward voltage per diode | I _F = 2.5 A | | | 0.52 | - | | | | |
| | $I_F = 5 A$ | T _J = 125 °C | | 0.58 | - | | | | |
| | I _F = 10 A | | | 0.65 | 0.70 | | | | |
| | V _B = 160 V | T _J = 25 °C | | 0.0006 | - | | | | |
| Reverse current at rated V_R per diode | $v_{\rm R} = 100 v$ | T _J = 125 °C | | 0.9 | - | mA | | | |
| | V 200 V | T _J = 25 °C | 'R (=/ | - | 0.05 | ШA | | | |
| | V _R = 200 V | T _J = 125 °C | | 2.2 | 8 | | | | |
| Typical junction capacitance | 4.0 V, 1 MHz | | CJ | 650 | - | pF | | | |

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 5 ms

| THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | | | | |
|--|---------------------------------|---|------|--|--|--|--|
| PARAMETER SYMBOL VX20202C UNIT | | | | | | | |
| Typical thermal resistance per device | R _{θJC} ⁽¹⁾ | 1 | °C/W | | | | |

Note

⁽¹⁾ Thermal resistance junction-to-case to follow JEDEC[®] 51-14 transient dual interface test method (TDIM)

| ORDERING INFORMATION (Example) | | | | | | | | | |
|--|------|---|---------|------|--|--|--|--|--|
| PREFERRED P/N UNIT WEIGHT (g) PACKAGE CODE BASE QUANTITY DELIVERY MODE | | | | | | | | | |
| VX20202C-M3/P | 2.03 | Р | 50/tube | Tube | | | | | |
| VX20202CHM3_A/P (1) | 2.03 | Р | 50/tube | Tube | | | | | |

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

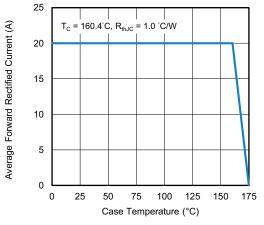


Fig. 1 - Maximum Forward Current Derating Curve

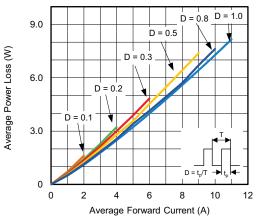


Fig. 2 - Average Power Loss Characteristics

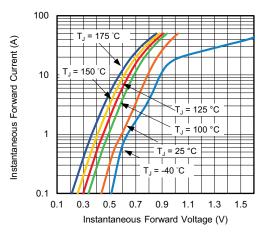


Fig. 3 - Typical Instantaneous Forward Characteristics

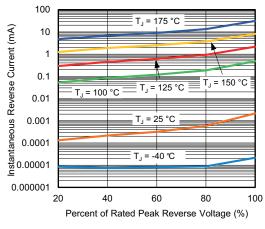


Fig. 4 - Typical Reverse Leakage Characteristics

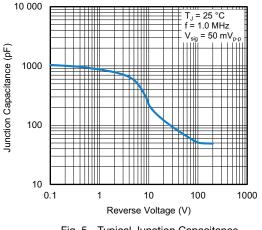


Fig. 5 - Typical Junction Capacitance

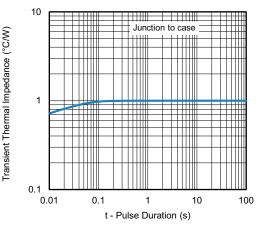


Fig. 6 - Typical Transient Thermal Impedance

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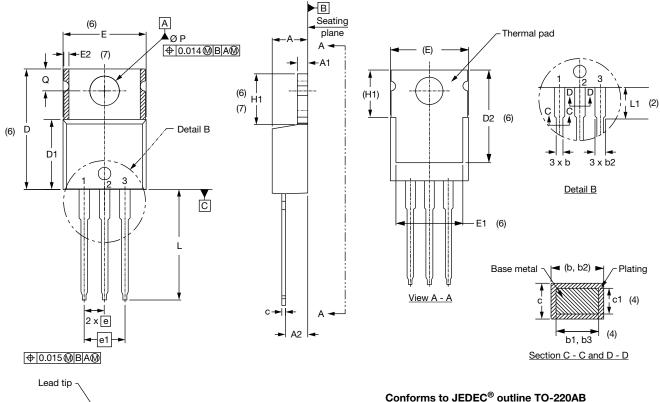
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VX20202C

Vishay General Semiconductor



DIMENSIONS in millimeters (inches) TO-220AB



neten Teten neten

Conforms to JEDEC[®] outline TO-220AB

| SYMBOL | MILLIMETERS | | INCHES | | NOTES | | OVMDOL | MILLIMETERS | | INCHES | | NOTES |
|--------|-------------|-------|--------|-------|-------|---|--------|-------------|-------|--------|-------|-------|
| | MIN. | MAX. | MIN. | MAX. | NOTES | | SYMBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| А | 4.25 | 4.65 | 0.167 | 0.183 | | | D2 | 11.68 | 12.88 | 0.460 | 0.507 | 6 |
| A1 | 1.14 | 1.40 | 0.045 | 0.055 | | | E | 10.11 | 10.51 | 0.398 | 0.414 | 3, 6 |
| A2 | 2.56 | 2.92 | 0.101 | 0.115 | | | E1 | 6.86 | 8.89 | 0.270 | 0.350 | 6 |
| b | 0.69 | 1.01 | 0.027 | 0.040 | | | E2 | - | 0.76 | - | 0.030 | 7 |
| b1 | 0.38 | 0.97 | 0.015 | 0.038 | 4 | | е | 2.41 | 2.67 | 0.095 | 0.105 | |
| b2 | 1.20 | 1.73 | 0.047 | 0.068 | | | e1 | 4.88 | 5.28 | 0.192 | 0.208 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | | H1 | 5.84 | 6.86 | 0.230 | 0.270 | 6, 7 |
| С | 0.36 | 0.61 | 0.014 | 0.024 | | | L | 13.52 | 14.02 | 0.532 | 0.552 | |
| c1 | 0.36 | 0.56 | 0.014 | 0.022 | 4 | | L1 | 3.32 | 3.82 | 0.131 | 0.150 | 2 |
| D | 14.85 | 15.25 | 0.585 | 0.600 | 3 | | ØР | 3.54 | 3.73 | 0.139 | 0.147 | |
| D1 | 8.38 | 9.02 | 0.330 | 0.355 | |] | Q | 2.60 | 3.00 | 0.102 | 0.118 | |

Notes

 $^{(1)}\,$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Dimension b1, b3 and c1 apply to base metal only

⁽⁵⁾ Controlling dimensions: inches

⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1

 $^{(7)}$ Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed

(8) Outline conforms to JEDEC[®] TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

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